

## **INCHANGE SEMICONDUCTOR**

# **isc** Silicon PNP Power Transistor

# **KTB1367**

### DESCRIPTION

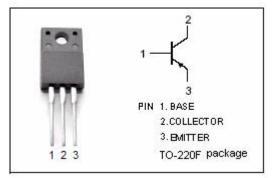
- Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -100V(Min)
- Collector Power Dissipation-:  $P_C$ = 30W@  $T_C$ = 25°C
- · Low Collector Saturation Voltage-
- : V<sub>CE(sat)</sub>= -2.0V(Max)@ (I<sub>C</sub>= -4A, I<sub>B</sub>= -0.4A)
- Complement to Type KTD2059
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

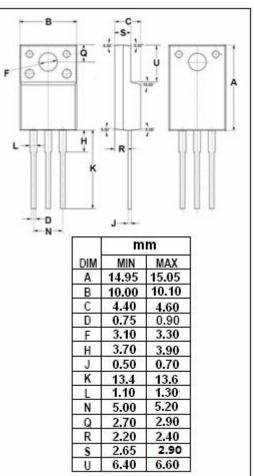
### **APPLICATIONS**

• Designed for general purpose applications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	-100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-100	V
V <sub>EBO</sub>	Emitter-Base Voltage -5		V
lc	Collector Current-Continuous	-5	A
l <sub>Β</sub>	Base Current-Continuous	-0.5	A
Pc	Collector Power Dissipation @Tc=25°C	30	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C





isc website: <u>www.iscsemi.com</u>



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### **ELECTRICAL CHARACTERISTICS**

#### Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA; I <sub>B</sub> = 0	-100			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -4A; I <sub>B</sub> = -0.4A			-2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -4A; V <sub>CE</sub> = -5V			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -100V; I <sub>E</sub> = 0			-100	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	40		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -4A; V <sub>CE</sub> = -5V	20			

### h<sub>FE-1</sub> Classifications

R	0	Y	
40-80	70-140	120-240	

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